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# Quantum mechanical studies of carbon structures

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# Quantum mechanical studies of carbon structures

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#### Abstract

Carbon nanostructures, such as nanotubes and graphene, are of considerable interest due to their unique mechanical and electrical properties. The materials exhibit extremely high strength and conductivity when defects created during synthesis are minimized. Atomistic modeling is one technique for high resolution studies of defect formation and mitigation. To enable simulations of the mechanical behavior and growth mechanisms of C nanostructures, a high-fidelity analytical bond-order potential for the C is needed. To generate inputs for developing such a potential, we performed quantum mechanical calculations of various C structures.

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# **NOMENCLATURE**

di dimer tri trimer ch chain tetra tetragon sq square

de diamond-cubic se simple-cubic

bcc body-centered-cubic fcc face-centered-cubic

hcp hexagonal-closely-packed

gra graphite grap graphene

MD molecular dynamics
DFT density functional theory
PAW projector-augmented-wave

VASP Vienna Ab initio Simulation Package

vdW van der Waals

GGA generalized-gradient approximation

PBE Perdew, Burke and Ernzerhof density functional

## 1. INTRODUCTION

Carbon nanostructures, such as nanotubes and graphene, are of considerable interest due to their mechanical and electrical properties. To develop defect free C nanostructures, predictive molecular dynamics (MD) simulations of C growth mechanisms are very valuable. Such simulations require a high-fidelity C interatomic potential [1]. To generate reference data for parameterizing the C potential, we performed quantum mechanical calculations to determine the cohesive energy and structural properties of various configurations of C. For convenience, we will use the following abbreviations to represent structures: di: dimer; tri: trimer; ch: chain; sq: square; tetra: tetragon; dc: diamond-cubic; sc: simple-cubic; bcc: body-centered-cubic; fcc: face-centered-cubic; hcp: hexagonal-closely-packed; gra: graphite; grap: graphene.

## 2. QUANTUM MECHANICAL METHODS

All density functional theory (DFT) calculations were performed within the spin-polarization formalism using the optB86b-vdW functional [2] and projector-augmented-wave (PAW) [3, 4] pseudopotentials. The optB86b-vdW functional was used because of its ability to capture dispersion interactions (van der Waals forces) which are essential for modeling the intramolecular interactions in C based systems (e.g. the interactions between graphene sheets in graphite); moreover, this functional has been shown to improve over transition generalized-gradient approximation (GGA) functionals (e.g. PBE) for a range of solids on the prediction of lattice constants, cohesive energies, and bulk moduli [2]. For all calculations a plane-wave cutoff energy of 500 eV was used and full geometry optimizations (ions and unit cell) were performed until all forces were smaller than 0.01 eV/Å. For bulk lattices, the Brillouin zone was sampled using a  $10 \times 10 \times 10$  gamma-centered Monkhorst-Pack grid [5]. For small clusters, the calculations are carried out in a 25 ų box using a gamma-point Brillouin zone. All calculations were performed within VASP 5.3.5 [6, 7, 8, 9].

## 3. RESULTS

The energies and atomic spacings of various clusters, consisting of four or less atoms for the elemental C are given in Table 1. The cohesive energies and atomic volumes of various elemental C lattice structures are given in Table 2. It should be noted that the experimental values for C structures [10, 11] are in good agreement.

Table 1. Cohesive energies  $E_c$  (eV/atom) and atom spacing r (Å) of various C clusters. For chain r values, the first value is the exterior bond length and the second number is the internal bond length.

Structure	С	
	$E_c$	r
tetra	-3.9410	1.5065
square	-4.6471	1.4664
trimer	-4.8444	1.3753
dimer	-3.4625	1.3127
chain	-5.2705	1.3175,
		1.2958

Table 2. Cohesive energies E<sub>c</sub> (eV/atom) and lattice constants a, c (Å) for selected lattices. Experimental values are given in parenthesis [10, 11]

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Structure		DFT		
	$E_{c}$	a,c		
bcc	-3.8272	2.3745		
dc	-8.0186	3.5619		
	(-7.38)	(3.56)		
fcc	-3.6094	3.0884		
gra	-8.0581	2.465, 6.3949		
	(-7.4)	(2.46,6.69)		
grap	-7.9919	2.4644		
hcp	-4.1203	1.71965, 6.1473		
sc	-5.2387	1.7517		

# 3. SUMMARY

This work presents a database of energies and geometric parameters for a range of structures for elemental C. The values are determined from DFT and were used for parameterizing interatomic potentials for MD simulations [1].

## 4. REFERENCES

- 1. X.W. Zhou, D. K. Ward, and M.E. Foster, An Analytical Bond-Order Potential for Carbon, in Journal of Computational Chemistry, vol. 36, pp1719-1735, 2015.
- 2. J. Klimeš, D. R. Bowler, and A. Michaelides, Van der Waals density functionals applied to solids, in *Physical Review B*, vol. 83, pp. 195131 1-13, 2011.
- 3. P. E. Blöchl, Projector augmented-wave method, in *Physical Review B*, vol. 50, pp. 17953-17979, 1994.
- 4. G. Kresse and D. Joubert, From Ultrasoft Pseudopotentials to the Projector Augmented-wave Method, in *Physical Review B*, vo. 59, pp. 1758-1775, 1999.
- 5. Hendrik J. Monkhorst and James D. Pack, Special Points for Brillouin-Zone Integrations, in *Physical Review B*, vol. 13, pp. 5188-5192, 1976.
- 6. G. Kresse and J. Hafner, *Ab initio* Molecular Dynamics for Liquid Metals, in *Physical Review B*, vol. 47, pp. 558-561, 1993.
- 7. G. Kresse and J. Hafner, *Ab initio* Molecular-Dynamics Simulation of the Liquid-Metal-Amorphous-Semiconductor Transition in Germanium, in *Physical Review B*, vol. 49, pp. 14251-4269, 1994.
- 8. G. Kresse and J. Furthmüller, Efficiency of Ab-initio Total Energy Calculations for Metals and Semiconductors Using a Plane-Wave Basis Set, in *Physical Review B*, vol. 6, pp. 15-50, 1996.
- 9. G. Kresse and J. Furthmüller, Efficient Iterative Schemes for Ab initio Total-Energy Calculations Using a Plane-Wave Basis Set, in *Physical Review B*, vol. 54, pp. 11169-11186, 1996.
- 10. J. D. H. Donnay and H. M. Ondik, *Crystal Data, Determinative Tables*, 3<sup>rd</sup> ed., Vol. 2 (inorganic compounds); available from the U.S. Department of Commerce, National Bureau of Standards, and Joint Committee on Power Diffraction Standards, U. S. A., 1973
- 11. I. Barin, Thermochemical Data of Pure Substances, VCH, Weinheim, 1993.

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